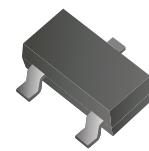


Small Signal Schottky Diodes

Comchip
SMD Diode Specialist

CDBH3-00340-G

Reverse Voltage: 40Volts
Forward Current: 30mA
RoHS Device



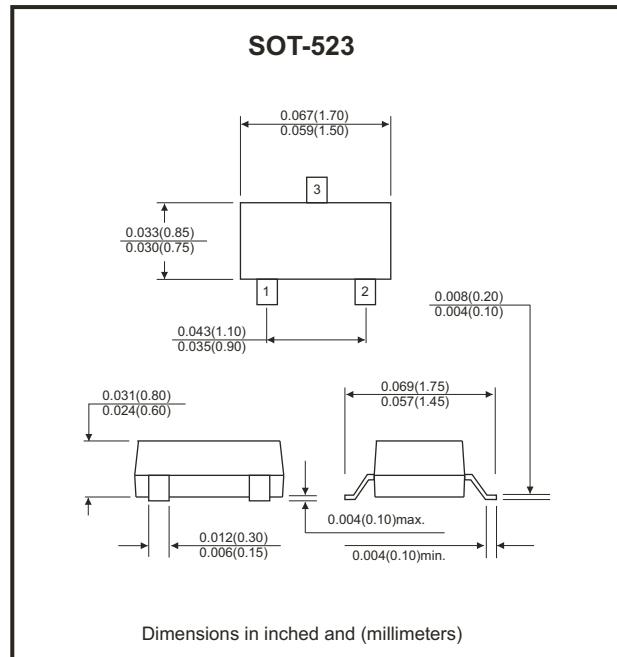
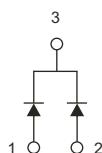
Features

- Designed for mounting on small surface.
- High speed switching application, circuit protection.
- Low turn-on voltage

Mechanical data

- Case: SOT-523, molded plastic.
- Terminals: Solder plated, solderable per MIL-STD-750, method 208.
- Approx. weight: 0.002 grams.

Equivalent circuit:



Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ.	Max	Unit
Repetitive peak reverse voltage		V _{RRM}			40	V
Reverse voltage		V _R			40	V
Average forward current		I _o			30	mA
Forward current, surge peak	8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}		200		mA
Power dissipation		P _D			150	mW
Storage temperature		T _{STG}	-40		+125	°C
Max. junction temperature		T _J			+125	°C

Electrical Characteristics (at Ta=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ.	Max	Unit
Forward voltage	IF=1mA	V _F			0.37	V
Reverse current	VR=10V	I _R			1	µA
Capacitance between terminals	f=1MHz, VR=1V	C _T		1.5	2	pF

RATING AND CHARACTERISTIC CURVES (CDBH3-00340C-G)

Fig.1 - Forward Characteristics

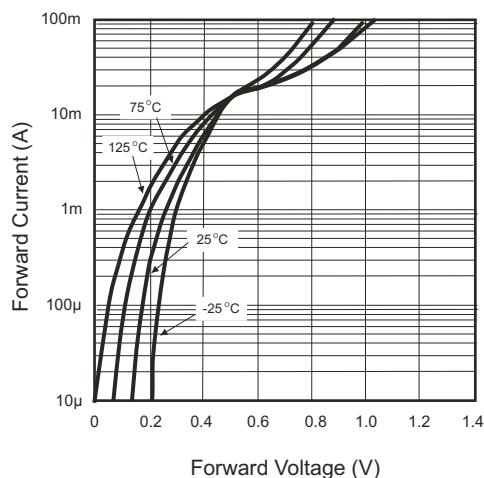


Fig.2 - Reverse Characteristics

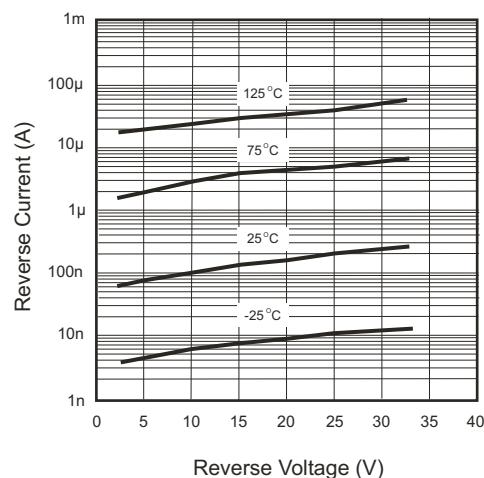


Fig.3 - Capacitance Between Terminals Characteristics

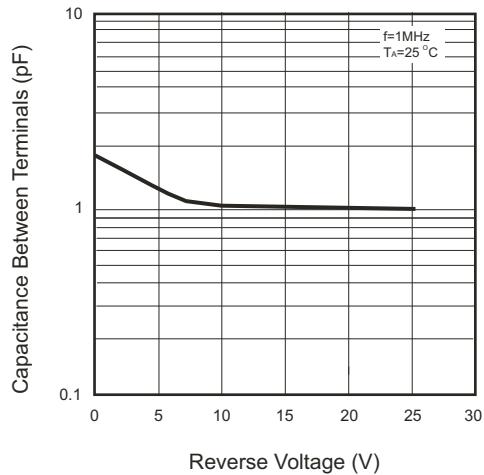


Fig.4 - Power Derating Curve

